

OVERVIEW

The SM8224B is a receiver and decoder that supports the Bellcore TR-NWT-000030 and SR-TSV-002476 standards calling number identification (caller ID) and call waiting dual-tone signals. It has separate caller ID signal and call waiting signal inputs, which allows the gain for each input to be adjusted independently. It is fabricated in CMOS and features a power-down function, realizing low power dissipation operation.

FEATURES

- TR-NWT-000030 and SR-TSV-002476 standards (Bellcore)
- Call waiting
- FSK decoder
- High input sensitivity
- Independent input gain adjustment for caller ID signal and call waiting signal inputs
- Power-down mode
- Crystal oscillator circuit built-in
- Single supply operation:4.5 to 5.5V
- Molybdenum-gate CMOS process

APPLICATIONS

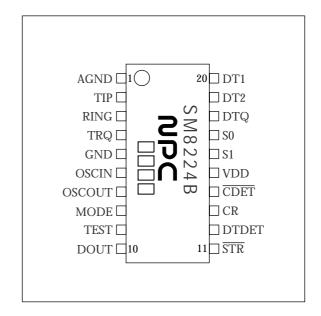
- Telephones, fax machines and modems that support pre- and mid-conversation information services
- Adapters for pre- and mid-conversation information service functions
- Telephone answering machines
- Facsimile machines
- Computer peripheral equipment

ORDERING INFORMATION

Device	Package
SM8224BM	20-pin SSOP
SM8224BS	20-pin SOP

PINOUT

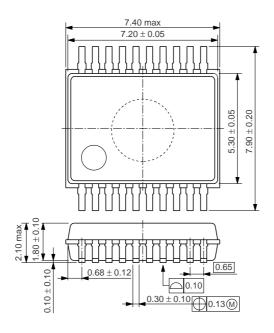
(Top view)

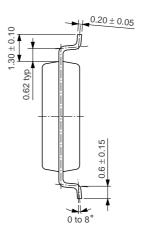


PACKAGE DIMENSIONS

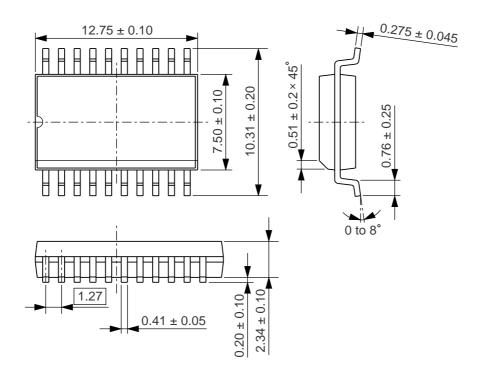
(Unit: mm)

20-pin SSOP

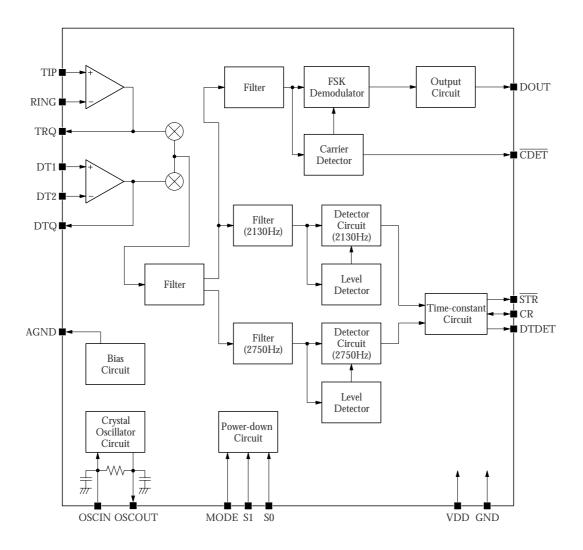




20-pin SOP



BLOCK DIAGRAM



SM8224B

PIN DESCRIPTION

Number	Name	1/0	Function
1	AGND	0	Analog ground output. Internal reference voltage (V _{DD} /2) output level
2	TIP	I	Tip input. Connected to the telephone line through a protection circuit
3	RING	I	Ring input. Connected to the telephone line through a protection circuit
4	TRQ	0	Input-stage amplifier gain-select output. Used to adjust the gain of the input-stage amplifier.
5	GND	-	Ground. Connected to the system ground potential.
6	OSCIN	I	Crystal oscillator input. The crystal oscillator element is connected between this pin and OSCOUT.
7	OSCOUT	0	Crystal oscillator output. The crystal oscillator element is connected between this pin and OSCIN.
8	MODE	ı	When MODE is HIGH, and S1 and S0 are both LOW, the device is in power-down state. See table 2.
9	TEST	-	TEST pin. Set OPEN when normal using.
10	DOUT	0	Data output. Demodulated FSK signal output. HIGH level output when CDET goes HIGH.
11	STR	0	Dual-tone confirmation output. Function is selected by SO and S1. See table 2. Dual-tone confirmation: Active-LOW output when dual tone detection signal passes through RC time constant delay circuit.
12	DTDET	0	Dual-tone detector output. HIGH-level output when dual tone is detected.
13	CR	1/0	Dual tone RC time constant circuit connection. The dual tone detection signal passes through the RC network to generate the \$\overline{STR}\$ signal.
14	CDET	0	FSK signal carrier detector output. LOW-level when active carrier is detected.
15	VDD	-	Supply
16	S1	I	Function select bit 1. Selects the device mode in combination with S0 and MODE. See table 2.
17	S0	I	Function select bit 1. Selects the device mode in combination with S1 and MODE. See table 2.
18	DTQ	0	Dual-tone signal input-stage amplifier output. Used to adjust the gain of the input-stage amplifier.
19	DT2	I	Dual-tone signal input-stage operational amplifier inverting input
20	DT1	I	Dual-tone signal input-stage operational amplifier non-inverting input

SPECIFICATIONS

Absolute Maximum Ratings

GND=0V

Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	V _{DD}		- 0.5 to 7.0	V
Input voltage range	V _{IN}		- 0.3 to V _{DD} + 0.3	V
Power dissipation	P _D		44	m W
Storage temperature range	T _{stg}		-40 to 125	°C

Recommended Operating Conditions

GND=0V

Parameter	Symbol	Condition —		Rating		Unit
Parameter	Symbol		min	typ	max	Unit
Supply voltage	V _{DD}		4.5	-	5.5	٧
Clock frequency	f _{CLK}		-	3.579545	-	MHz
Clock frequency accuracy	$\Delta f_{\mathbb{C}}$		-0.1	-	+0.1	%
Operating temperature	T _{opr}		-20	-	85	°C

Electrical Characteristics

 $V_{DD} = 5.0V \pm 0.5V, GND = 0V, f_{CLK} = 3.579545 MHz, T_a = -20 \ to \ 85^{\circ}C \ unless \ otherwise \ noted.$

Parameter	Symbol	Condition		Rating		Unit
Parameter	Symbol	Collattion	min	typ	max	UIIII
Supply current consumption	I _{D D}	No analog signal input, no output load, S1 = 0V, S0 = V _{DD} , MODE = 0V	-	-	8.0	m A
Power-down current	I _{DPD}	No analog signal input, other inputs = V_{DD} or 0V, no output load, S1 = 0V, S0 = 0V, MODE = V_{DD}	-	-	15	μА
MODE, S0, S1 LOW-level input voltage	V _{IL1}		-	-	0.3V _{DD}	V
MODE, S0, S1 HIGH-level input voltage	V _{IH1}		0.7V _{DD}	-	-	V
OSCIN LOW-level input voltage	V _{IL2}		-	-	0.3V _{DD}	٧
OSCIN HIGH-level input voltage	V _{IH2}		0.7V _{DD}	-	-	٧
DOUT, STR, DTDET, CR, CDET LOW-level output current	I _{OL}		2	-	-	m A
DOUT, STR, DTDET, CR, CDET HIGH-level output current	Іон		-	-	-0.8	m A
TIP, RING, DT1, DT2, MODE, S1, S0 input leakage current	I _{IN}		– 1	-	1	μA

AC Electrical Characteristics

Measurement conditions: $R1 = 430k\Omega$, $R2 = 34k\Omega$, $R3 = 390k\Omega$, $C1 = 0.22\mu F$

FSK decoder

 V_{DD} = 5.0V \pm 0.5V, GND = 0V, f_{CLK} = 3.579545MHz, T_a = -20 to 85°C unless otherwise noted.

Parameter	Symbol	Condition		Rating	Unit	
Parameter	Symbol	Condition	min	typ	max	UIII
Input sensitivity			-	-43	CD _{ON}	dBm
S/N ratio ¹	FSKSNR		20	-	-	dB
Carrier detection sensitivity	CD _{ON}		-	-43	-37.78	d B m
Carrier non-detection sensitivity	CD _{OFF}		-50	-46	-	dBm
Oscillator frequency	f _{CLK}		typ — 0.1%	3.579545	typ + 0.1%	MHz

^{1.} Mark signal and SPACE signal are same level. Noise: Random noise from 200Hz to 3400Hz.

Dual tone detector

 V_{DD} = 5.0V \pm 0.5V, GND = 0V, f_{CLK} = 3.579545MHz, T_a = -20 to 85°C unless otherwise noted.

Parameter	Symbol	Symbol Condition Rating		Rating		Unit
raiailietei	Symbol	Condition	min	typ	max	Oiiit
Frequency (low frequency)	f _L		-	2130	-	Hz
Frequency (high frequency)	f _H		-	2750	-	Hz
Detection frequency deviation			1.1	-	-	%
Non-detection frequency deviation			3.5	-	-	%
Detection sensitivity			-37.78	-	-	d B m
Non-detection sensitivity			-	-	-43.78	d B m
Signal level deviation			-	-	6	dB

Note: (S0, S1, MODE) = (V_{DD}, 0V, 0V)

Input-stage amplifier Characteristics

 $V_{DD} = 5.0V \pm 0.5V, GND = 0V, f_{CLK} = 3.579545MHz, T_a = -20 \ to \ 85^{\circ}C \ unless \ otherwise \ noted.$

Parameter	Symbol	Symbol Condition Rating			Unit	
ratameter	Symbol	Condition	min	typ	max	Oiiit
Input leakage current	I _{IN}		-	-	1	μΑ
DC open-loop voltage gain	G _{OL}		30	-	-	dB
Unity gain frequency	f _C		80	-	-	kHz
Load capacitance	CL		-	-	100	pF
Load resistance	R _L		50	-	-	kΩ

Timing Characteristics

FSK decoder

 $V_{DD} = 5.0V \pm 0.5V, GND = 0V, f_{CLK} = 3.579545MHz, T_a = -20 \ to \ 85^{\circ}C \ unless \ otherwise \ noted.$

Parameter Symbol		Condition	Rating	Unit		
ratallietei	3 9 111 10 1	Condition	min	typ	max	UIIIL
Power-down release to start-up time	t _{DOSC}		-	5	-	m s
Carrier detection ON time	t _{DAQ}		2.5	-	10	ms
Final data to carrier detection OFF time	t _{DCH}		3	-	15	m s

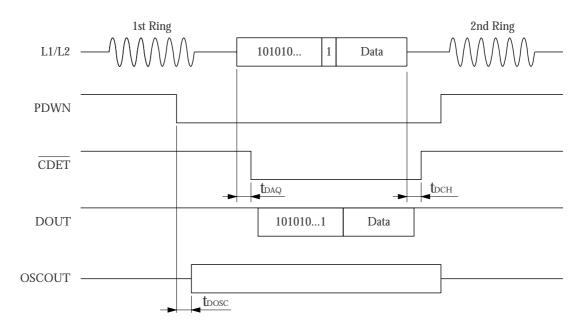
Output timing)

 V_{DD} = 5.0V \pm 0.5V, GND = 0V, f_{CLK} = 3.579545MHz, T_a = -20 to 85°C, FSK input data = 1200 \pm 12 baud unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit
ralameter	3 y 111 b 01	Condition	min	typ	max	
STR, DOUT rise time	t _{r0}		-	-	200	ns
STR, DOUT fall time	t _{f0}		-	-	200	ns
Input/output delay	t _{IDD}	Input to DOUT	-	-	5	ms
DOUT data rate			1188	1200	1212	baud

TIMING DIAGRAMS

FSK demodulator timing



PDWN is an internal signal (set by S0, S1, MODE)

Output timing

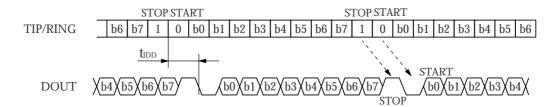
DOUT



STR



Data timing



FUNCTIONAL DESCRIPTION

The SM8224B receiver with caller ID service conforms to the Bellcore standards. It incorporates FSK demodulator and dual-tone detection functions in a single chip. It has a dedicated dual-tone signal input so that the FSK signal input amplification and dual-

tone signal input amplification can be set independently. This allows systems can be easily constructed that provide pre- and mid-conversation information services.

FSK Demodulator

Calling number identification service is sent as an FSK signal, and the SM8224B FSK demodulator processes this signal.

The FSK signal conforms to the following Bellcore standard.

Table 1. FSK signal

Parameter	Description
Modulation type	Continuous-phase binary frequency-shift- keying
Logic "1" data (mark)	1200 ± 12 Hz
Logic "0" data (space)	2200 ± 22 Hz
Signal level (mark)	−32 to −12 dBm
Signal level (space)	−36 to −12 dBm
Data transfer rate	1200 ± 12 baud

Table 2. Function select

\$1	S0	MODE	Function	STR
LOW	LOW	HIGH	Power-down	HIGH
HIGH	LOW	LOW	Dual-tone detection from DT1/DT2 ¹	LOW (dual tone confirmation)
LOW	HIGH	LOW	FSK and dual-tone detection from TIP/RING	LOW (dual tone confirmation)
HIGH	HIGH	LOW	FSK detection from TIP/RING	HIGH
LOW	LOW	LOW	Test mode ²	

^{1.} DT1, DT2, DTQ are active in this mode only.

Note: S1, S0, MODE setting should be used from above combination except Test mode.

Dual Tone Detector

When using mid-conversation information services, 2 mixed signals of 2130Hz and 2750Hz are sent on lines L1 and L2. The SM8224B detects the 2 signals from the background noise. It uses 2 separate high-order filters with center frequencies of 2130Hz and 2750Hz to detect the presence of the signal frequencies.

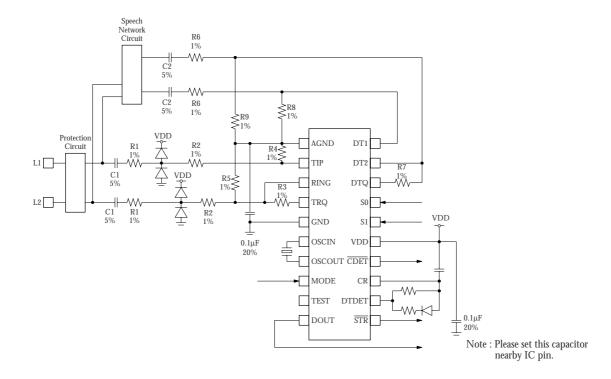
In series with the filters are level detectors. When the input level exceeds the preset rating, the signal is

detected. When the input level is below the rating, the signal is not detected.

If both the 2130Hz and 2750Hz signals are simultaneously detected, DTDET goes HIGH and starts charging the time constant circuit comprised by an external capacitor and external resistor. When the time constant circuit voltage rises above a fixed voltage level, $\overline{\text{STR}}$ signal goes LOW to indicate dual tone detection.

^{2.} Test mode should not be used.

TYPICAL APPLICATION CIRCUIT



Symbol	Rating ¹	Unit
R ₁	330	kΩ
R ₂	27	kΩ
R ₃	220	kΩ
C ₁	0.001	μF
R ₄	47.5	kΩ
R ₅	60.4	kΩ
R ₆	430 + 34	kΩ
R ₇	390	kΩ
C ₂	0.22	μF
R ₈	52.3	kΩ
R 9	60.4	kΩ

1. Circuit values are preliminary.

NIPPON PRECISION CIRCUITS INC. reserves the right to make changes to the products described in this data sheet in order to improve the design or performance and to supply the best possible products. Nippon Precision Circuits Inc. assumes no responsibility for the use of any circuits shown in this data sheet, conveys no license under any patent or other rights, and makes no claim that the circuits are free from patent infringement. Applications for any devices shown in this data sheet are for illustration only and Nippon Precision Circuits Inc. makes no claim or warranty that such applications will be suitable for the use specified without further testing or modification. The products described in this data sheet are not intended to use for the apparatus which influence human lives due to the failure or malfunction of the products. Customers are requested to comply with applicable laws and regulations in effect now and hereinafter, including compliance with export controls on the distribution or dissemination of the products. Customers shall not export, directly or indirectly, any products without first obtaining required licenses and approvals from appropriate government agencies.



NIPPON PRECISION CIRCUITS INC.

4-3, Fukuzumi 2-chome Koto-ku, Tokyo 135-8430, Japan Telephone: 03-3642-6661

Facsimile: 03-3642-6698

NC9910AE 2000.02